

The interface between HOPG and 1-butyl-3-methyl-imidazolium hexafluorophosphateC. Müller,^{a,b} K. Németh,^c S. Vesztergom,^d T. Pajkossy^e and T. Jacob^{a,f}**Abstract**

The interface between highly oriented pyrolytic graphite (HOPG) and 1-butyl-3-methyl-imidazolium hexafluorophosphate (BMIPF₆) has been studied using cyclic voltammetry, electrochemical impedance spectroscopy, immersion charge measurements and *in-situ* scanning tunneling microscopy (*in-situ* STM). The results are compared with those obtained with Au(100) in BMIPF₆ (*Phys.Chem.Chem.Phys.*, 2011, **13**, 11627). The main result is that the high frequency capacitance spectra on the two systems are similar to each other, however at low frequencies some slow interfacial processes cause the appearance of a second capacitance arc on Au(100), which is absent for HOPG. The slow processes are attributed to the rearrangement of the Au surface structure and to the formation of ionic liquid adlayers — these are visualized by *in-situ* STM.

Introduction

Ionic liquids (ILs)^{1,2,3,4} are organic salts which are liquid (molten) at ambient temperatures. They are often referred to as “designer solvents”: due to the large variety of the different possible cation/anion combinations, the physicochemical properties of ILs can be fine-tuned in order to meet the requirements of specific applications. ILs present a versatile alternative to more common solvents because of their broad (sometimes up to 4–5 V wide) electrochemical window and high thermal stability. They are non-flammable, exhibit virtually zero vapour pressure and many chemical species have a good solubility in them. From an electrochemical point of view, their most promising field of application is the design of energy-storage devices such as batteries and supercapacitors.^{5,6,7} In addition, ionic liquids (especially the air- and water-stable imidazolium-based ones⁸) can also be used as electrolytic media for the electrodeposition of highly reactive materials^{9,10}. In order to facilitate these applications, a general understanding of the physical chemistry of metal | IL in-

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terfaces is required; this is the reason why ionic liquids are in the focus of a continuously growing interest in both experimental and theoretical research.^{11,12,13}

From the fundamental research point of view, the key point of studying metal | IL interfaces is the use of electrodes with well-defined surface structures in combination with high-purity ILs. In accordance with this statement, the interface of gold single crystals with a well-defined surface orientation was recently studied in 1-butyl-3-methyl-imidazolium hexafluorophosphate (BMIPF₆),^{14,15,16} in a home-made guanidinium-based IL,¹⁷ and in 1-butyl-3-methyl-imidazolium bis(trifluoromethylsulfonyl)imide (BMITf₂N).¹⁸ In these studies the Faradaic reaction-free potential regions of the metal | IL electrodes were identified and characterized by cyclic voltammetry (CV), while electrochemical impedance spectroscopy (EIS) was employed in order to determine the interfacial capacitance. The potential-dependent capacitance spectra, as well as the surface images acquired by scanning tunnelling microscopy (*in-situ* STM) allowed for the characterization of the interfacial structure and of the different processes occurring therein. By means of immersion charge measurements, the potential of zero total charge (*pztc*) of metal | IL interfaces was also determined, providing further information on the chemical nature of the interfacial adlayers.

Interestingly, the results of our previous studies^{14–18} contradicted in one crucial point the existing theories of metal | IL interfaces. Kornyshev's original theory¹⁹ and some related works^{20,21,22,23,24} (see also Ref. 25 for a review) attempt to describe ionic liquid systems on the basis of a lattice gas model by taking into consideration Coulomb interactions as well as the finite volume of the ionic species. These models^{19,20,21,22} predict bell- or camel-shaped differential capacitance vs. electrode potential curves, however – as it was also pointed out by Kornyshev *et al.* in a recent study²³ –, the numerical values significantly overestimate the experimentally determined capacitance data. This discrepancy may be resolved by assuming a lower-than-unity ionic dissociation factor in ILs:^{23,26,27,28,29,30} as the mean-field capacitance in Kornyshev's model depends linearly on the ionic concentration, a lower ionic concentration could, in principle, bring the results of theory and experiment closer to each other.

However, one contradiction still remains to be dealt with: namely, that time does not appear as a variable in the existing double-layer theories of IL systems, and as a consequence, the theoretically predicted $C(E)$ functions are always frequency-independent. This is in strong contrast to the results of our previous impedance studies, which explicitly pointed out that the measured capacitance heavily depends on the frequency used for its determination. For example, it was shown that the complex plane capacitance spectra of the Au(100) | BMIPF₆ interface exhibit a characteristic “double-arc” feature.¹⁵ As it is shown in this paper, explaining the double-arc behaviour of the Au(100) | BMIPF₆ system is possible by means of a comparison to the capacitance spectra recorded on highly oriented pyrolytic graphite (HOPG) | BMIPF₆.

In the present work we thus present a basic electrochemical characterization of the interface of HOPG in BMIPF₆, which is then compared to those results obtained with Au(100) in the same IL.^{15,16} The focus is on the following questions: *i.*) What is the physical background of the double-arc on the capacitance spectrum? *ii.*) Which processes could be responsible for the appearance of the two different time constants? *iii.*) In general, how to measure the double layer capacitance of interfaces involving ILs?

Experimental methods

Materials

The experiments were carried out with a HOPG sample of square shape (12 mm × 12 mm, Veeco, USA). Prior to each measurement, the HOPG surface was prepared by mechanical exfoliation (*i. e.*, the topmost graphite layers were removed by scotch-tape).³¹ BMIPF₆ was purchased from Merck KGaA in the highest available quality (purity ≥ 99.5%, water ≤ 100 ppm, halides ≤ 100 ppm). The ionic liquid was vacuum-dried for 24 hours at 80 °C and purified with a 0.3 nm molecular sieve.³² The electrochemical measurements were carried out in a glovebox (MBraun LabStar) under N₂ atmosphere, and a protective N₂ blanket was maintained over the cell also during the *in-situ* STM studies.

Cells and basic measurements

CV and EIS experiments were conducted using an IM6 potentiostat (Zahner Messsysteme) in a custom-made, cylindrical, closed Kel-FTM cell with a total volume of 0.3 cm³. The HOPG working electrode (WE) and the polycrystalline gold sheet counter electrode (CE) comprised the two end-faces of the cylinder. Their parallel position ensured a strictly homogeneous current distribution, which is a necessary condition of accurate high-frequency impedance measurements. A silver wire of 0.5 mm diameter covered by AgCl was applied as a *quasi*-reference electrode (RE), placed in-between the working and counter electrodes, parallel to both. Unless it is stated otherwise, the electrode potential values reported in this paper are all meant *vs.* this reference electrode. Test measurements with dummy cells were performed in order to determine phase shifts due to the potentiostat and cables.

For studying temperature dependences, a heatable copper block was mounted on the cell. A temperature control with an accuracy of ± 1 °C was achieved, with an accessible range of 25–130 °C.

For the determination of *pztc*, a Kel-FTM cell comprising two parts were designed. The bottom part held the HOPG sample to which a 3 mm high ring was assembled in order to form a vessel. The upper part was a tube, in the wall of which a Pt wire and an AgCl-coated Ag wire were inserted (these were used as counter and reference electrodes, respectively). By using a safety pipette ball (Peleus ball) mounted on the top end, the tube was filled through its porous lower end with BMIPF₆. After a certain time, the tube was positioned over the HOPG surface (at an approximate distance of 2 mm), the potential control was switched on, and the cell was flood with the electrolyte by exerting pressure on the Peleus ball. The wetting of HOPG took less than 1 second, and the current involved in the creation of the electrochemical double layer was measured. Note that using this setup we could not achieve the level of cleanliness and time resolution of the setup dedicated for immersing Au(100) into BMIPF₆.³³

Impedance measurements and spectrum analysis

The EIS measurements (recording of spectra at different potential setpoints) were carried out by giving a special attention to the reproducibility of the results. First a spectrum was recorded at an electrode potential close to the open circuit value, between 100 mHz and 1 MHz (sinusoidal perturbation with 5 mV amplitude). Several hours later, the same measurement was repeated, and the resulting spectra were compared. If the impedance plots featured no significant differences, spectra were also measured at other potential setpoints. The sequence of impedance measurements was started at 400 mV, and the setpoint values were decreased in 200 mV steps to –400 mV. The direction of potential stepping was changed at this point: the next applied setpoint was of –300 mV, and then the potential was gradually stepped back to 300 mV (again in 200 mV steps). Thus, imped-

ance spectra over the voltage range between 400 and -400 mV were recorded (at a resolution of 100 mV), and the cyclic sequence definition provided additional means to check the reproducibility of the spectra. (In a stable system, the shape of an impedance spectrum should depend only on the actual potential, and not on the potential at which the electrode was previously conditioned.) The invariance of the spectra for the Kramers–Kronig transformation³⁴ was also checked in each case, and the low frequency data points for which the invariance did not hold, were removed.

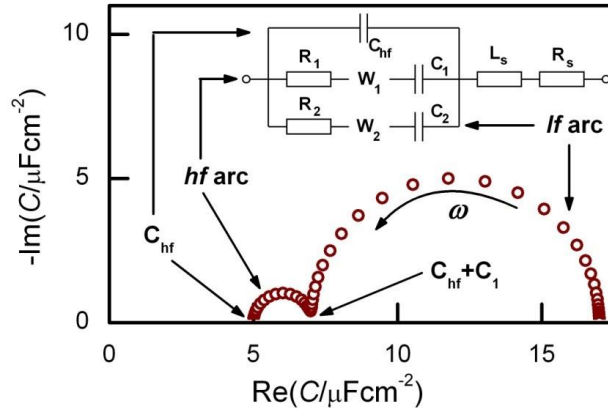


Fig. 1 Equivalent circuit used for fitting the spectra and features of the capacitance spectra of the interface. *lf* and *hf* indicate high and low frequency, respectively.

The measured spectra were analyzed by fitting the parameters of an equivalent circuit using modulus weighting.³⁵ In our previous studies^{14,15,16,17,18} we found that the impedance spectra of most metal | IL interfaces can well be fitted by an equivalent circuit shown in the inset of Fig. 1. Here the three-branched part represents the interfacial impedance; R_s denotes the electrolyte resistance, and an empirical, formally inductive L_s term (of either sign, with a corresponding impedance of $i\omega L_s$) accounts for the minor high frequency errors which occur due to the various imperfections of the measurement setup.³⁶ (Here $\omega = 2\pi f$ is the angular frequency, and f the frequency of the sinusoidal perturbation.) In many cases the $R_2W_2C_2$ branch of the interfacial impedance is either missing, or some of its elements may be *quasi* short-circuits. The W_1 and W_2 elements are empirical terms, their *pseudo*-Warburg-impedance name comes from the $\sqrt{i\omega}$ frequency dependence involved. In most cases the impedance spectra – measured over 5-7 orders of magnitude of frequency – could be well fitted with 4-7 parameters of the complete circuit of Fig. 1.

In Fig. 1, and also later in this paper we visualize impedances as capacitance spectra of the interface, $C(\omega)$. This is calculated from the interfacial admittance $Y_i(\omega)$ as $C(\omega) = Y_i(\omega)/(i\omega)$. Since both R_s and L_s affect impedance spectra at the high frequency end, $C(\omega)$ can be calculated as

$$C(\omega) = 1/[i\omega(Z(\omega) - Z(\omega \rightarrow \infty))] = 1/[i\omega(Z(\omega) - R_s - i\omega L_s)] \quad (1)$$

In the case of a circuit of Fig. 1, the $C(\omega)$ function, plotted on the complex plane (as an Argand-diagram or Nyquist-plot) consists of two arcs as illustrated there.

Single-frequency capacitance scans

$C(E)$ curves were measured by the application of single sinusoid perturbations (with 5 mV amplitude and 1 kHz frequency) superimposed on a stair-case-like voltage scan. Before each scan, the R_s

and L_s terms of the bulk impedance (see Fig. 1) were determined by recording a single impedance spectrum, and by carrying out equivalent circuit fitting for the high-frequency parts. The impedance values were then converted (Eq. (1)) to complex capacitances, $C(E)$. Double layer capacitance is identified as the real part of $C(E)$, provided that the imaginary part is negligibly small.

STM measurements

The STM measurements were carried out on a Topometrix Discoverer TMX 2010 instrument. The STM tips were prepared by the galvanic etching of platinum/iridium wires (80/20) in 3.5 M NaCN. In order to reduce the Faradaic current and the stray capacitance of the tip, a BASF electrophoretic paint was applied to the tip, except for its very end. The STM cell had a volume of 0.2 cm³ and was open to enable a 4 electrode configuration. An Ag/AgCl wire was acting as a *quasi*-reference electrode and a Pt wire was used as a counter electrode. Constant current scanning with a typical set-point of 1 nA was carried out. The cell was filled with the IL inside a glove-box, and was transferred to the STM in a small chamber providing N₂ protection.

Results

Cyclic voltammetry

The electrochemical stability window of HOPG | BMIPF₆ was identified by cyclic voltammetry, as shown in Fig. 2(a). The CV in the narrowest potential range (measured between ± 400 mV) exhibited featureless capacitive behavior, although the CV was not perfectly symmetrical to the horizontal axis. After broadening the scanned range to -0.6 V in the negative and $+1.5$ V in the positive direction, the system still remained fairly stable, and the only notable change was the appearance of a pair of spikes at $+1.2$ V (see also the results of *in-situ* STM studies below). With further extension of the potential vertices, high negative and positive Faradaic currents were triggered below -2.8 V and above $+2.0$ V, respectively — hence the “electrochemical window” is about 4.8 V broad.

The charging current measured on HOPG | BMIPF₆ is lower by a factor of 3 to 5 compared to that measured on Au(100) | BMIPF₆,¹⁶ and the same applies for the *dc* capacitance — defined as the average charging current divided by the scan rate —, that has an approximate value of 7 $\mu\text{F}/\text{cm}^2$.

The cyclic voltammograms taken between -0.4 and $+0.4$ V remain stable, even following a long-time conditioning at a certain potential. As an example, Fig. 2(b) shows CVs, which were recorded before and after an impedance measurement that took three hours at $E = 0$ V: the charging current is only slightly increased, and the small Faradaic currents appearing at positive potentials are also negligible.

Impedance measurements

At first sight the impedance spectra measured between -0.4 and $+0.4$ V are capacitive. A closer inspection of the Nyquist representation of the interfacial capacitance (calculated according to Eq. (1)) reveals, however, a single-arc shape (see Figs. 3(a), 4 and 6(a)). Accordingly, the equivalent circuit of the interface is basically two-branched (upper inset of Fig. 3(a), the R_2 element adds a little correction only). The quality of the fits is good, as it is illustrated by the residuals plotted in Fig. 3(b). In general, the spectra obtained from HOPG | BMIPF₆ can be fitted with the same accuracy as those

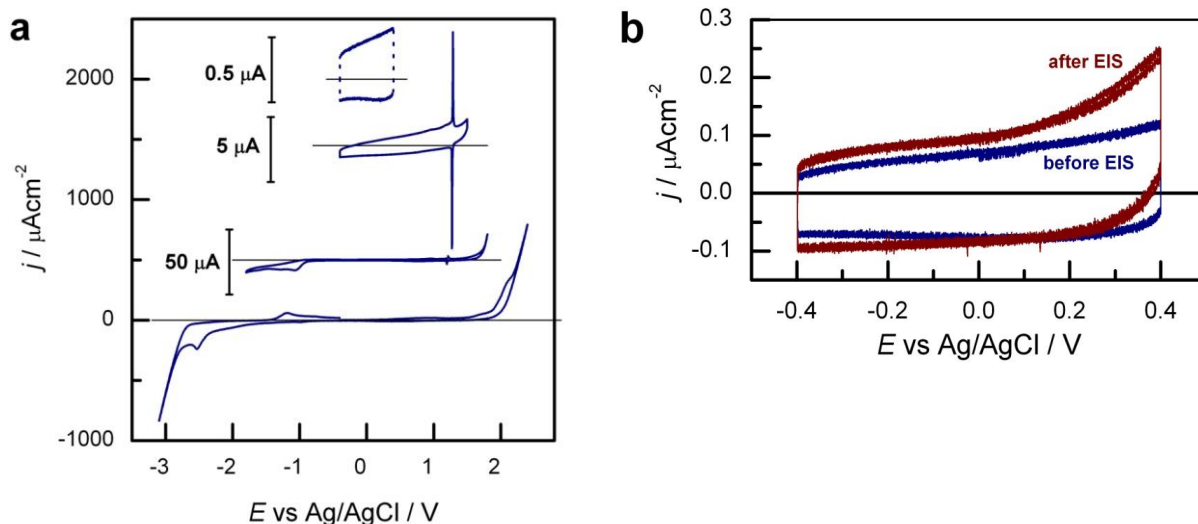


Fig. 2 (a) CVs at 50 mV/s with varied potential limits. For the sake of visibility, the CVs are shifted along the ordinate and magnified as indicated. (b) CVs recorded at 10 mV/s before and after an EIS measurement (lasting for 3 hours) was carried out at 0 V vs. Ag | AgCl.

obtained from Au(100) | BMIPF₆; $\chi^2 \approx 10^{-5}$ for both cases. The fitting residuals in Fig. 3b are just as little as they are in Fig. 2b of Ref. 15. We note that this equivalent circuit was found appropriate also when potential and temperature dependences were studied (see the results of Figs. 4 and 6).

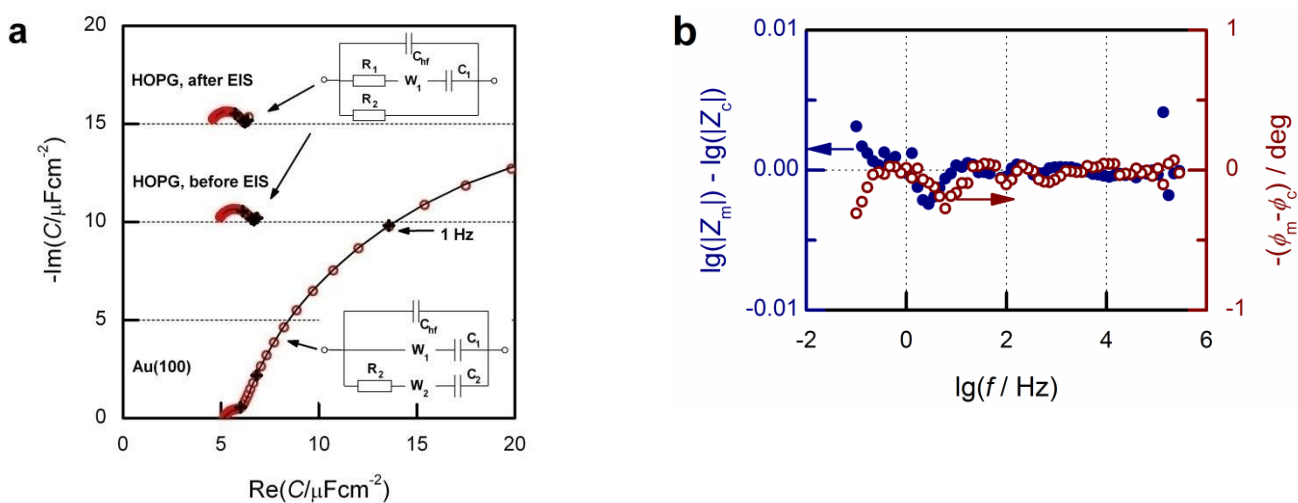


Fig. 3 (a) Complex plane plot of the interfacial capacitance spectra, in the 0.1 Hz – 1 kHz range, measured at 0 V on HOPG and Au(100). The two HOPG spectra were measured before and after the application of a potential sequence (Fig. 4), and demonstrate the high stability of the system. The Au(100) spectrum is taken from Fig. 5 of Ref. 16. Open symbols represent the measured spectrum points, to which the solid lines were fitted using the equivalent circuits of the insets. The points measured at 0.1, 1, 10 and 100 Hz are marked by crosses. The spectra are shifted along the ordinate for reasons of clarity. (b) Fitting residuals for the “HOPG, before EIS series” spectrum of the (a) part of the figure. The full and open symbols are differences of impedance magnitudes and phases, respectively.

The high frequency limit of the capacitance spectra for HOPG and Au(100) are approximately the same, both having a value of $\approx 5\mu\text{F}/\text{cm}^2$. Also the medium frequency part is similar for the two systems: the middle branch of the interfacial equivalent circuit (insets of Fig. 3a) contains a *pseudo*-Warburg impedance (W_1) and a capacitance (C_1), eventually also a resistor (R_1). The origin of the *pseudo*-Warburg impedance is still unclear and has been used only in an empirical manner. For “real” Warburg impedances, this element is due to the diffusion of some minority components, which can be excluded in case of our system. R_1 and C_1 deliver a time-constant in the order of 20 ms.

The main difference between the capacitance spectra of HOPG and Au(100) lies in the low frequency range. The second arc on the capacitance spectrum, which is present for Au(100), is missing at the same frequency range for HOPG (Fig. 3(a)). Accordingly, the impedance of the ($R_2W_2C_2$) branch on HOPG is so high that only an R_2 element of very high value (and also of high uncertainty) can be determined by fitting.

Here we note that the single-arc shape of the capacitance spectra is reproducible. The two spectra shown in Fig. 3(a), recorded before and after a long series of measurements, are practically identical; however, the actual capacitance values – similarly to what was shown by cyclic voltammetry – are slightly increased following a long-time conditioning at several potentials.

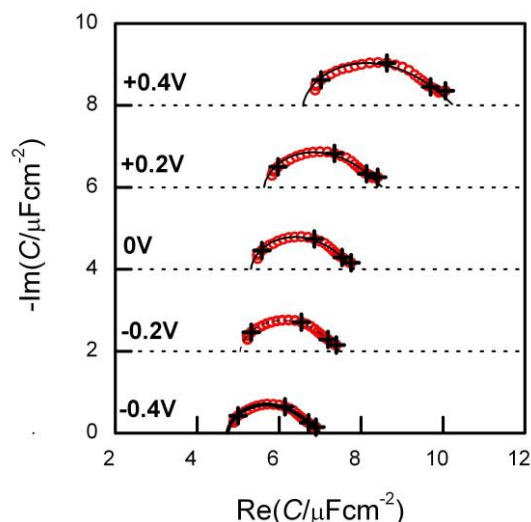


Fig. 4 Potential dependence of capacitance spectra of HOPG in BMIPF₆: measured data points (open symbols) combined with fitted ones (solid lines). Crosses are points at 1 kHz, 100 Hz, 10 Hz and 1 Hz frequencies. The spectra are shifted along the ordinate for clarity.

The capacitance spectra of HOPG exhibit only a slight potential dependence in the -0.4 V to $+0.4\text{ V}$ potential range, as shown in Fig. 4. The high-frequency capacitance (C_{hf}) lies around $5\mu\text{F cm}^{-2}$, and seems to increase with positive potentials. C_1 is in the order of magnitude of $2\mu\text{F cm}^{-2}$ and shows a similar potential dependence. The fitted values of $C_{\text{hf}}(E)$ and $C_{\text{hf}}(E) + C_1(E)$ are plotted for HOPG in Fig. 5, where for the sake of comparison the dataset of Fig. 5 in Ref. 16 (measured on Au(100) in BMIPF₆) is also included.

Although the shape of the curves in Fig. 5 seems to be somewhat different for the two electrodes, it should be noted that in terms of numerical values these differences are rather low ($<1\mu\text{Fcm}^{-2}$ for $C_{\text{hf}}(E)$, and $<2\mu\text{Fcm}^{-2}$ for $C_{\text{hf}}(E)+C_1(E)$).

The potential dependence of C_{hf} can be directly determined by single-frequency/scanned-potential impedance measurements as well. This overcomes the rather time-consuming recording of entire impedance spectra. As it is shown in Fig. 4, 1 kHz is a sufficiently high frequency, where $C_{\text{hf}}(E) \approx \text{Re}(C(E))$. Interfacial capacitances as function of potential determined at 1 kHz are shown in Fig. 5(b). This curve exhibits the same increase of C_{hf} with potential, as obtained from the impedance spectra.

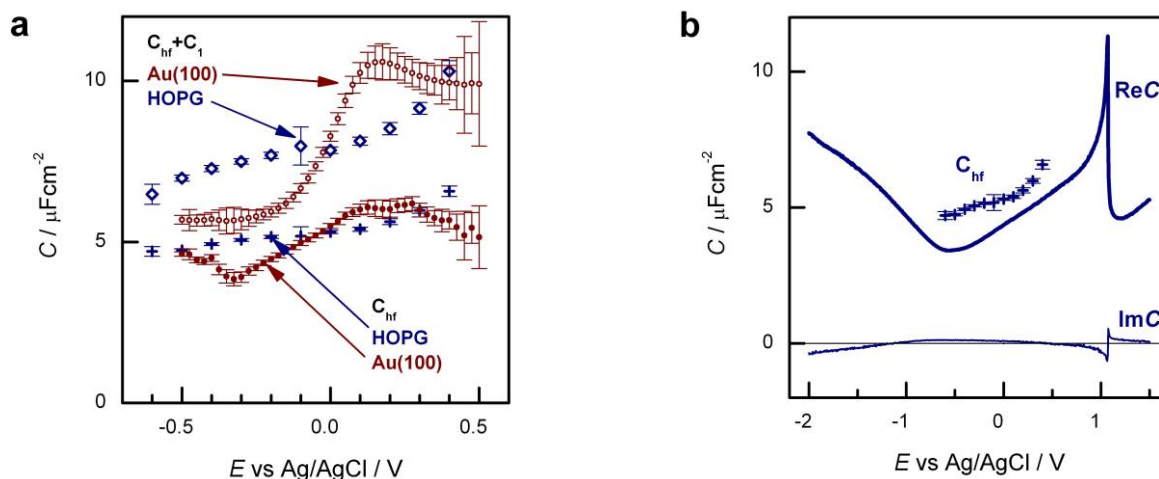


Fig. 5 (a) Fitted capacitances as a function of potential. Crosses and diamonds: C_{hf} and $C_{\text{hf}} + C_1$ for HOPG, respectively. Full and open circles show the re-plotted dataset of Fig. 5 of Ref. 16 for C_{hf} and $C_{\text{hf}} + C_1$ on Au(100), respectively. (b) Solid lines: $\text{Re}(C)$ and $\text{Im}(C)$ measured at 1 kHz frequency and a 2.8 mV/s effective scan-rate on HOPG. The C_{hf} dataset of (a) was re-plotted here for comparison.

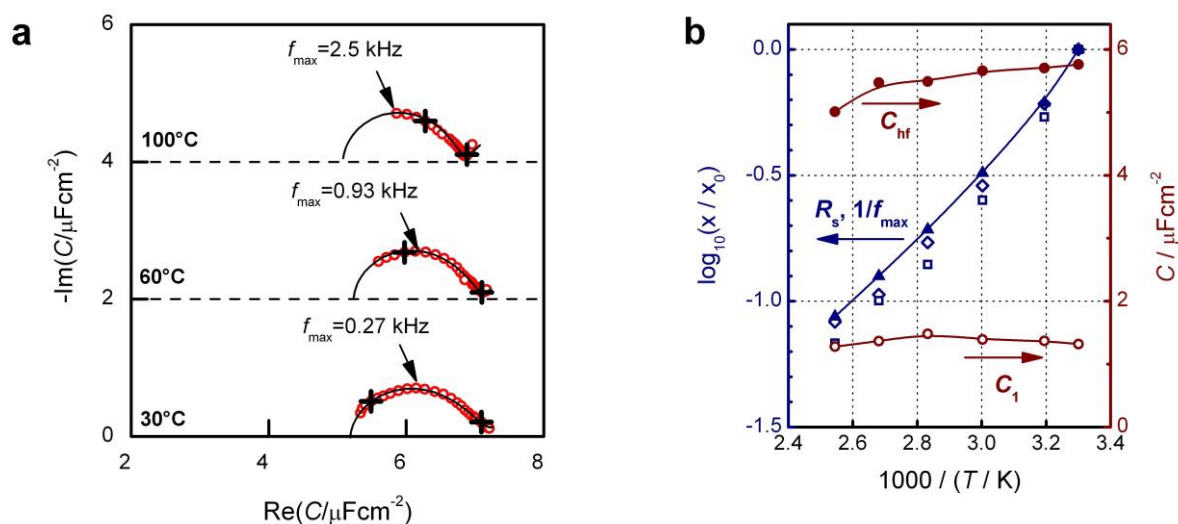


Fig. 6 (a) Capacitance spectra of HOPG in BMIPF₆ at the indicated temperatures, recorded at 0 V. Open symbols and solid lines represent measured and fitted data, respectively. Crosses are points at 1 kHz and 10 Hz frequencies; f_{max} , the characteristic frequency of the $R_1W_1C_1$ branch (the frequency of the arc's topmost point) is indicated. The spectra are shifted along the ordinate for clarity. (b): Fitted parameters as a function of reciprocal temperature. Left axis: x represents any of R_s , R_1C_1 (open diamonds) and $1/f_{\text{max}}$, (open squares), all normalized to their 30 °C value, x_0 . Right axis: C_{hf} (full circles), C_1 (open circles).

As in the case of Au(100) | BMIPF₆,¹⁶ we attempted to identify the origin of the equivalent circuit elements. Therefore, we measured impedance spectra at different temperatures (between room temperature and 120 °C). It is apparent that all the capacitance spectra in Fig. 6(a) are of single-arc shape and the high and low frequency limits have little if any temperature dependence (Fig. 6(b), dataset belonging to the right axis). We note that an increase of double layer capacitances with increasing temperature was previously reported,^{25,37} and the C_{hf} values measured on Au(100) | BMIPF₆ (cf. Figs. 6 and 7 of Ref. 16) also show the same behaviour. However, the relative changes of C_{hf} are negligible compared to the temperature dependence of the resistive elements of the circuit.

R_s and the characteristic frequency (reciprocal of the time constant) of the arc do depend on temperature. The latter dependence is apparent in Fig. 6(a): the capacitance spectra points shift clockwise along the arc with increasing temperature. The time constant of the arc can be given in two simple approximations: as the reciprocal frequency of the topmost point of the arc, f_{max} , or as the R_1C_1 product. These values are rather similar to each other and depend strongly on the temperature. Their temperature dependence is similar to that of R_s , as shown in Fig. 6(b), data linked to the left axis. Note that the slope of the $\log(R_s)$ vs. $1/T$ curve is related to the activation energy – in the order of 30 kJ/mol – of ion transport in the bulk.

Immersion experiments

We obtained the immersion charge by integrating the current following the contact of HOPG with BMIPF₆ under controlled potential; $pztc$ is the potential at which the integration charge is just zero. The integrated current transients recorded at different immersion potentials are shown in Fig. 7. With HOPG, the immersion charge is much smaller than with Au(100). As it is shown in the inset, the charge – calculated for the first second; *i. e.*, the time of the wetting – is in the $1 \mu\text{C}/\text{cm}^2$ order of magnitude in the 100 mV vicinity of the $pztc$. This low value is in accordance with the small capacitances ($C_{\text{hf}} + C_1 \approx 8 \mu\text{F}/\text{cm}^2$) obtained from impedance spectra (since capacitance = charge change divided by potential change). As both the long- and short-time values of the $q(t)$ function reveal, the $pztc$ lies somewhere between -0.3 V and -0.1 V .

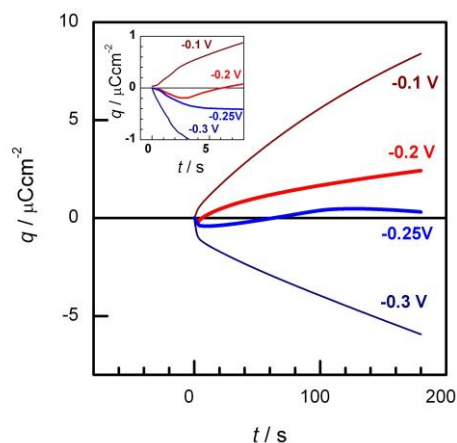


Fig. 7 Integrated immersion current transients at potentials indicated. Inset: the charge in the first seconds.

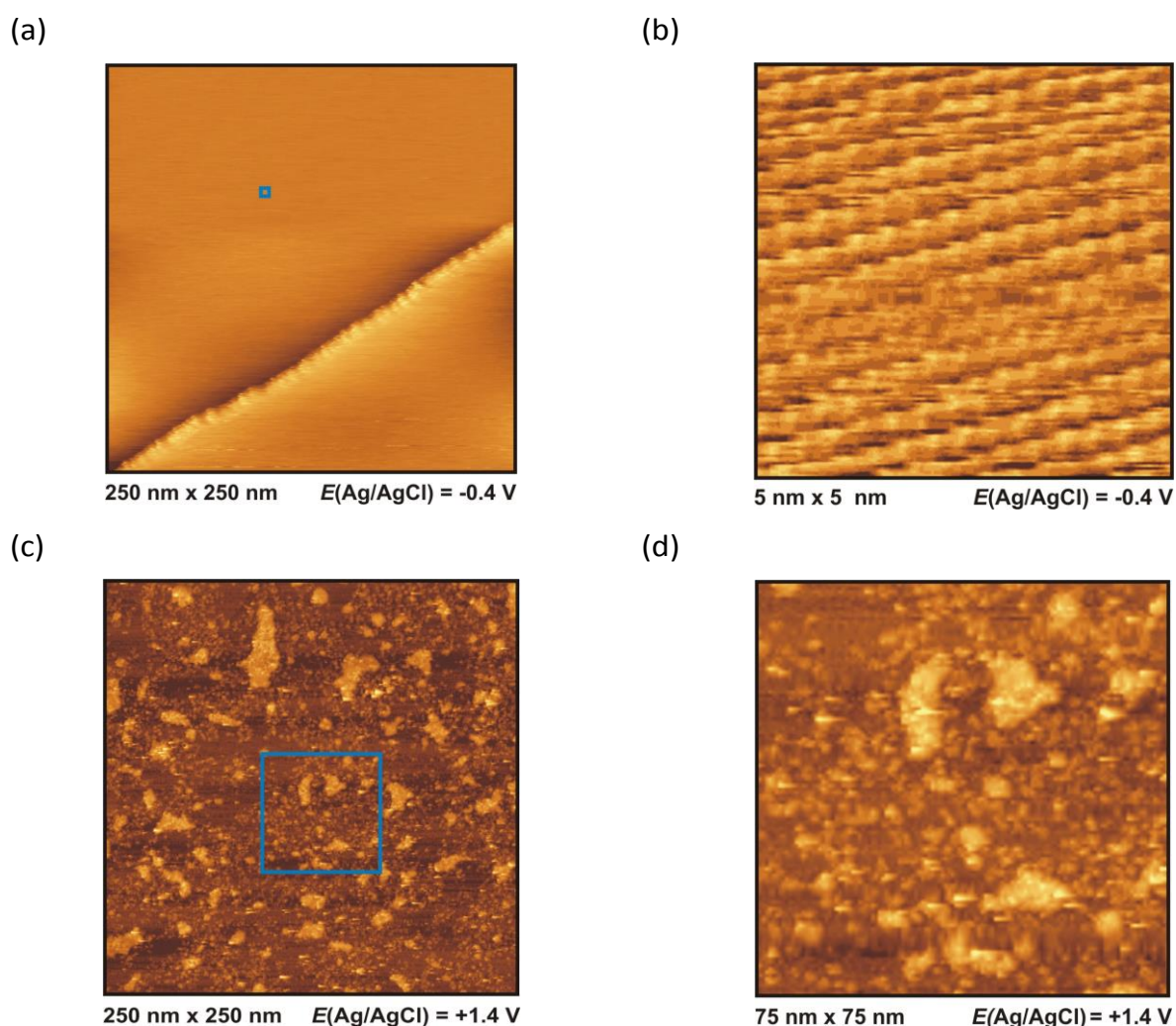


Fig. 8 STM images of HOPG in BMIPF₆ at potentials and magnifications as indicated. First and second rows: negative and positive to the *pztc*. The images of the *rhs* column have been made on the areas marked by squares on *lhs* images.

In-situ STM

In-situ STM studies were accomplished in the stability range of HOPG in the IL. The open circuit potential (approx. -0.1 V vs. Ag | AgCl) was typically chosen as starting potential. A cathodic potential excursion to -0.4 V exhibits large terraces with a step height of (0.36 ± 0.05) nm (Fig. 8(a)), which approximately coincides with that of HOPG,³⁸ 0.335 nm.

At this potential the STM imaging is stable and little if any changes of the surface appears for several hours. An enlargement of the terraces shows an ordered adlayer (Fig. 8b) formed by the IL, which is eventually enriched in BMI⁺ cations, since the potential is somewhat more negative than the *pztc*. Spots are aligned in straight lines, revealing an ordered adlayer of the ionic liquid on HOPG. These spots have a distance of 0.38 nm to each other, which is larger by a factor of 1.5 compared to a typical in-plane lattice constant of 0.246 nm for HOPG.

At potentials more positive than $+1.2$ V (*i.e.*, more positive than the location of the spike pair in Fig. 2(a)), the character of the surface immediately changes and nanometer-sized islands of different shapes appear (Figs. 8(c) and 8(d)). Their height is around 0.3 nm (smaller particles) and 0.6 nm

(bigger, brighter particles). The height of the bigger particles is in accordance with the observation of IL “droplets” for this system by AFM.³⁹ To understand features at +1.2 V, we mention the following findings: First, +1.2 V is much more positive than the $pztc$, so anions are closer to the surface than cations. Second, the spikes can be observed neither in BMITf₂N nor in a 1:1 mixture of BMIPF₆ and BMITf₂N.

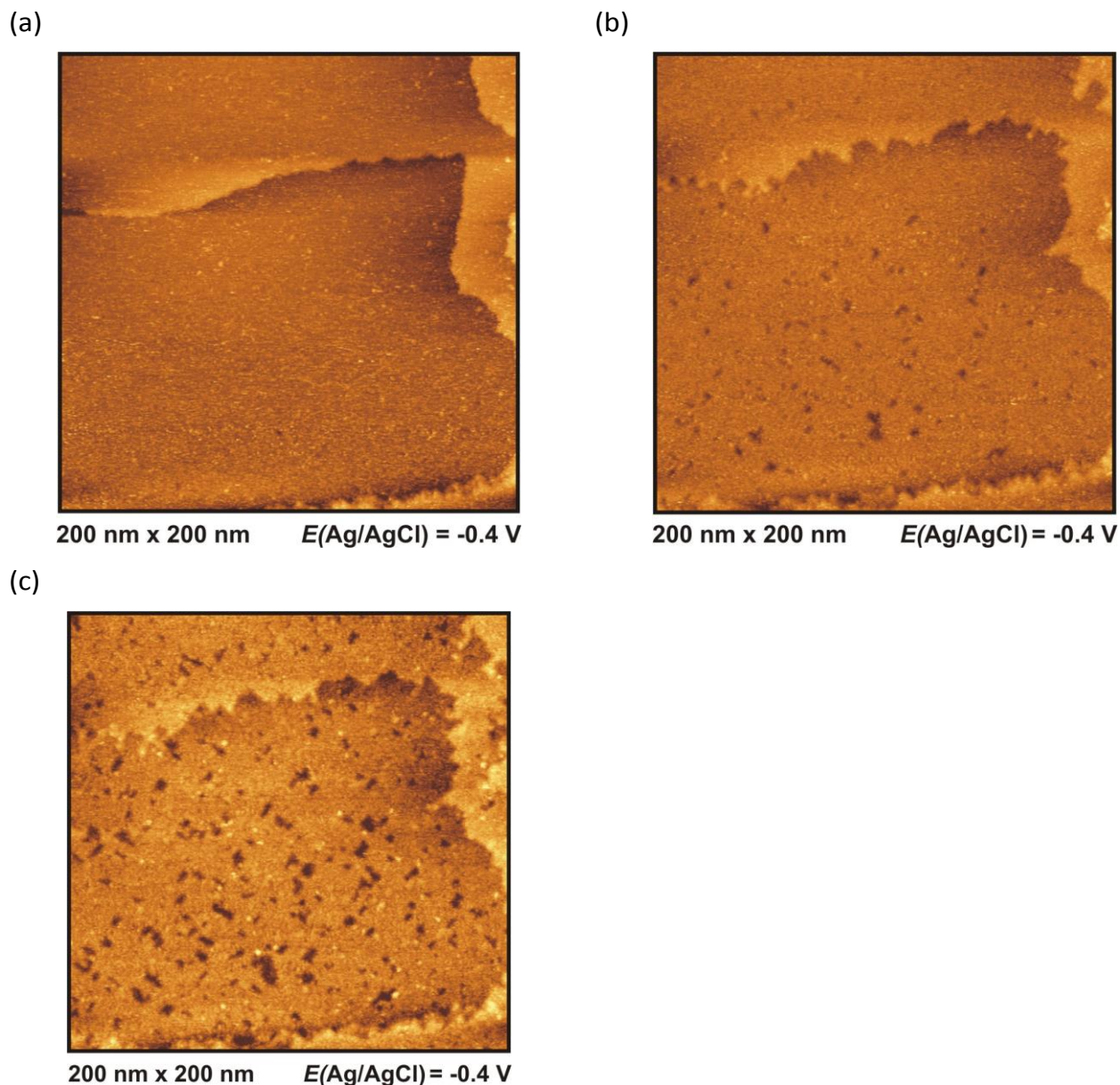


Fig. 9. Au(100) in BMIPF₆: series of STM images showing the time-dependent formation of holes in the surface. The images (a), (b) and (c) were taken immediately after, 6 minutes after and 30 minutes after placing the electrode to -0.4 V .

Third, as seen in Fig. 5(b), the $\approx 2 \mu\text{F}/\text{cm}^2$ difference of $\text{Re}(C)$ at the two sides of the peak at about +1.2 V indicates a significant change of the double layer. Hence, we attribute these findings to some phase transition of a PF_6^- adlayer.

To demonstrate that Au(100) is unstable compared to HOPG, the *in-situ* STM measurement with Au(100) reported in Ref. 16 has been repeated at a somewhat different potential. Fig. 9(b) of

Ref. 16 displayed small holes (etch pits), which were formed at -0.8 V. The evolution of the etch-pits is shown in the three images of Fig. 9. At the beginning, a surface with terraces and steps is visible. Within 30 min, the formation of mono-atomic deep pits, (0.26 ± 0.05) nm, in the terrace could be observed, which are presumably caused by slow etching and dissolution processes of the gold surface in BMIPF₆ (Figs. 9(b) and 9(c)). A “corrosion” process of similar kind was also reported in previous studies with imidazolium-based ILs^{16,18,40} or pyrrolidinium-based ILs⁴¹ on Au(100) and Au(111), respectively.

Discussion

Capacitance measurements

The main finding is the different character of interfacial capacitance spectra of HOPG and Au(100) in BMIPF₆. Whereas for Au the spectra exhibit two arcs, in case of HOPG the low frequency arc is missing (Fig.3(a)). The properties of the high frequency arc are rather similar for the two electrodes. For modeling the HOPG interface, the essential branches of the equivalent circuit are those containing C_{hf} and $R_1-W_1-C_1$. For Au(100), however, the branch $R_2-W_2-C_2$ additionally enters the picture. This difference is in accord with the *in-situ* STM images of the two systems: the HOPG surface is stable (cf. Fig. 8(a) and (b)), whereas on Au(100) a slow rearrangement of the surface proceeds (in a certain potential range, cf. Fig. 9). We attribute the properties of the high frequency arc to the behavior of interfacial IL layers that is common for both systems. The single-arc spectra as those shown in Figs. 4 and 6 and the capacitances plotted in Fig. 5(b) correspond to the double layer of a stable, rearrangement-free conductor in an ionic liquid.

The significance of a single-arc double layer capacitance needs some explanation: Since its introduction, double layer capacity has always been regarded as a quantity which depends on potential, electrode and electrolyte chemical properties, but its independence of frequency has rarely been questioned. In general, there exist three major cases when frequency-dependence of the double layer capacitance appears. First, it may be a consequence of some surface-inhomogeneity;⁴² second, due to some adsorption process of minority components of the electrolyte.⁴³ The third case is the appearance of single-arc capacitance spectra in classical, aqueous electrochemical systems, like in Pt-group metals in binary electrolytes⁴⁴; probably the presence is the most obvious in HCl solutions on Rh(111)⁴⁵ and Pt(100).⁴⁶ In these cases the arcs are associated with H⁺ or Cl⁻ movements between the outer and inner Helmholtz planes.

In the present study a fourth case of frequency dependence shows up: double layer capacitance is a single arc on the complex plane, which signifies some rearrangement of the double layer. The limiting values, C_{hf} and the $C_{hf} + C_1$ sum are the capacitances in the “frozen” and “relaxed” states of the double layer; the frequency of the topmost point represents a rate of the rearrangement process. This rate exhibits temperature dependence rather similar to that of bulk conductivity, probably due to the similar activation energy of molecular movements at the interface and within the IL bulk. We refrain from giving a molecular level explanation of the rearrangement.

At present, we do not know which of C_{hf} and $C_{hf} + C_1$ should be compared with the theoretical predictions. The existing theories^{19,20,21,22,23,24}, unfortunately, do not account for frequency dependence, and the predicted values are much larger than any of our C_{hf} or $C_{hf} + C_1$ values. In addition, we obtain no “bell-shape” or “camel-shape” $C(E)$ curves. Of course, one should keep in mind that due to different experimental methods, cell geometries, chemicals and electrodes in general it is difficult to compare results obtained in different laboratories.^{11,25,37,47,48,49}

A comment on capacitance measurements with electrodes other than HOPG: Whereas to determine C_{hf} is always possible by taking a high frequency limit of the capacitance, determining the $C_{hf} + C_1$ sum is possible only if the high frequency part can be well-fitted by the equivalent circuit of Fig. 1(a). In most of our studies with Au(100) electrodes, the high frequency arc was always clearly visible on complex-plane plots (cf. Fig. 3 of Ref. 16, Fig. 2b of Ref. 17 or Fig. 4 of Ref. 18). The exceptions are the spectra measured at elevated temperatures (e.g. in Fig. 6 of Ref. 16) where the interfacial processes (as the ones imaged above in Fig. 8) cause the high-frequency arc to be masked by the low-frequency one. Even in this case determination of C_{hf} is still possible with good accuracy.

Were the interfacial capacitance spectra for HOPG and Au(100) the same at any potential and temperature, we would conclude that the only role of the electrode is to provide the electric field upon the double layer. As the data displayed in Fig. 5(a) show, some small differences of the spectra exist, thus there are also other-than-electrostatic (“chemical”) interactions between the electrodes and the IL.

In-situ STM

In general, the STM images of HOPG in ILs are of lower quality than those obtained in air or in aqueous solutions. This is usually attributed to a strong binding of the IL ions to HOPG and to an eventual thermal drift of the tip.⁵⁰ These effects may hinder the reliable determination of structure geometries. Bearing in mind the above considerations, the periodicity seen in the micrograph of Fig. 8(b), recorded at potentials somewhat negative to the $pztc$, has two possible explanations. It may be attributed to a distorted HOPG surface, but also to an ordered, cation-rich adlayer. In the latter case the characteristic length – that is about 1.5 times larger than the lattice constant of HOPG – implies a more dense packing than that predicted by MD simulations.¹⁰ In Ref. [10], a defective 2D-hexagonal lattice of the adsorbed ions with a lattice spacing approximately four times larger than that of HOPG is determined. The discrepancy between the theoretical predictions of [10] and our experimental observations is a current research task in our institute and new simulation models are intended to be developed using our distinguished parameters. The appearance of patches has already been reported in Ref. 51 as the formation of thin films, nanometer-sized “drop-lets” and “drop-on-layer” structures of this ionic liquid. Films which cover the surface with a thickness up to 2 nm – corresponding to 4 IL layers – seem to be solid and indicate that IL molecules are organized into various micro-morphologies at room-temperature.⁵¹ Theoretical studies confirmed the existence of spatial heterogeneities at the interface due to the formation of polar and non-polar domains of the IL-molecules, as well as the existence of highly compressible alternating multilayers.^{52,53,54,55,56}

At very high negative potentials we could not find ordered superstructures such as those exist on Au(100) in BMIPF₆, where ordered double-row structures of the cations could be observed (Fig. 9. of Ref. 16). Ordering could be detected on HOPG in OMITf₂N at very negative potentials in a combined STM, AFM and DFT study⁵⁰. However, at these potentials, apparently, the HOPG and the BMI cations do not fit to each other and the double-row ordering of the cations is not possible for this electrode-cation combination.

At +1.4V, that is positive of the characteristic CV spikes, formation of islands is observed (Figs. 8(c) and 8(d)). The height is around 0.3 nm and 0.6 nm for the smaller and larger islands, respectively, implying probably mono- and bilayer-high islands. Taking also into account that the sharp peaks appear only in pure BMIPF₆ — i.e. the CV spikes mark some phase transition of the PF₆⁻ adlayer — these islands are probably PF₆⁻ rich domains. Another confirmation of this assumption is the fact

that the molecule size of this octahedron-sized ion is around 0.32 nm, which implies probably mono- and bilayer-high islands.

The connection of slow capacitive processes with surface rearrangement processes of single crystalline Au in ILs was put forward by Drüscher and coworkers recently.⁴⁹ They reported fast, slow and an ultra-slow sub-Hz capacitive processes for Au(111) in 1-butyl-1-methylpyrrolidinium-tris(pentafluoroethyl)trifluorophosphate (Py_{1,4}FAP). The ultra-slow capacitive contribution was assumed to be related to a vacancy formation in the surface. This assumption is in line with our present study: their “ultra-slow” capacitive process corresponds to our low frequency arc; the vacancy formation is a similar surface rearrangement process visualized by the *in-situ* STM image series of Fig. 9. We note that pit formation has also been reported for Au(100) in BMIBF₄.⁴⁰

Conclusions

The HOPG | BMIPF₆ interface has been studied in correspondence to our previous investigation of Au(100) | BMIPF₆.¹⁶ The main observation is the similarity of the high-frequency part of the capacitance spectra on the two systems. In contrast, the capacitance behavior at low frequencies is markedly different, which is attributed to the different stability of the two surfaces. As *in-situ* STM images reveal, the HOPG surface is stable, whereas the Au(100) surface is continuously rearranged; step edges move, etch pits are formed, the initially uniform crystal face corrodes. These “corrosion” processes modify the low-frequency impedance/capacitance: a resistive-capacitive branch (empirically R₂-W₂-C₂) parallel to the double layer capacitance elements appears in the equivalent circuit of Fig. 1.

From a double-layer capacity point of view, the C_{hf} | (R₁-W₁-C₁) elements are the main terms of the equivalent circuit being dominant at high frequencies of the capacitance spectra. Since the arc’s parameters (including the temperature dependences) are similar for HOPG and Au(100), we attribute this arc to the interfacial layer of the IL. Since C_{hf} and C_{hf} + C₁ are the limiting values of capacitance at high and low frequency, respectively, we regard these two quantities as double-layer capacitances characterizing the “frozen” and “relaxed” states. As far as we know, at the moment no metal | IL double layer theory exists by which C_{hf}, and C_{hf} + C₁ could be interpreted.

Whereas the HOPG is stable under IL, *in-situ* STM images reveal different IL structures at different potentials. At potentials somewhat negative of the *pztc*, an ordered structure on the surface could be observed, which has a 1.5 times larger lattice constant than that of HOPG. At +1.4V, that is, positive of characteristic CV spikes — marking probably some phase transition of the PF₆⁻ adlayer — formation of islands occurs.

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